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SEMICONDUCTOR PHYSICS

- 042001 Unipolar resistive switching of Au⁺-implanted ZrO₂ films** (4 pages)
Liu Qi, Long Shibing, Guan Weihua, Zhang Sen, Liu Ming, and Chen Junning

SEMICONDUCTOR MATERIALS

- 043001 Optical properties in 1D photonic crystal structure using Si/C₆₀ multilayers** (3 pages)
Chen Jing, Tang Jiyu, Han Peide, and Chen Junfang
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Zhou Xiaowei, Li Peixian, Xu Shengrui, and Hao Yue
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Xu Shengrui, Hao Yue, Duan Huantao, Zhang Jincheng, Zhang Jinfeng, Zhou Xiaowei, Li Zhiming, and Ni Jinyu
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Zhang Huafu, Lei Chengxin, Liu Hanfa, and Yuan Changkun

SEMICONDUCTOR DEVICES

- 044001 Optimized design of 4H-SiC floating junction power Schottky barrier diodes** (3 pages)
Pu Hongbin, Cao Lin, Chen Zhiming, and Ren Jie
- 044002 ⁶⁰Co γ -rays irradiation effect in DC performance of AlGaIn/GaN high electron mobility transistors** (5 pages)
Gu Wenping, Chen Chi, Duan Huantao, Hao Yue, Zhang Jincheng, Wang Chong, Feng Qian, and Ma Xiaohua
- 044003 Considerations of dopant-dependent bandgap narrowing for accurate device simulation in abrupt HBTs** (4 pages)
Zhou Shouli, Xiong Deping, and Qin Yali
- 044004 Degradation of ultra-thin gate oxide LDD NMOSFET under GIDL stress** (4 pages)
Hu Shigang, Hao Yue, Cao Yanrong, Ma Xiaohua, Wu Xiaofeng, Chen Chi, and Zhou Qingjun
- 044005 A new level-shifting structure with multiply metal rings by divided RESURF technique** (5 pages)
Liu Jizhi and Chen Xingbi
- 044006 Photo-sensitive characteristics of negative resistance turn-around occurring in SIPTH** (4 pages)
Ji Tao, Yang Licheng, Li Hairong, He Shanhu, and Li Siyuan
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Liu Xiang, Wei Fuxiang, and Liu Hui
- 044008 A high-efficiency high-power evanescently coupled UTC-photodiode** (4 pages)
Zhang Yunxiao, Liao Zaiyi, Zhao Lingjuan, Zhu Hongliang, Pan Jiaoping, and Wang Wei
- 044009 Microwave frequency detector at X-band using GaAs MMIC technology** (4 pages)
Zhang Jun, Liao Xiaoping, and Jiao Yongchang
- 044010 Design and fabrication of a terminating type MEMS microwave power sensor** (4 pages)
Xu Yinglin and Liao Xiaoping
- 044011 Thermal analysis and test for single concentrator solar cells** (4 pages)
Cui Min, Chen Nuofu, Yang Xiaoli, Wang Yu, Bai Yiming, and Zhang Xingwang
- 044012 High-performance micromachined gyroscope with a slanted suspension cantilever** (4 pages)
Xiao Dingbang, Wu Xuezhong, Hou Zhanqiang, Chen Zhihua, Dong Peitao, and Li Shengyi

(Continued on inside back cover)

SEMICONDUCTOR INTEGRATED CIRCUITS

- 045001** **Design of a 24–40 GHz balanced low noise amplifier using Lange couplers** (4 pages)
Zhang Zongnan, Huang Qinghua, Hao Mingli, Yang Hao, and Zhang Haiying
- 045002** **A cross-coupled-structure-based temperature sensor with reduced process variation sensitivity** (7 pages)
Tie Meng and Cheng Xu
- 045003** **An ultra-low-power CMOS temperature sensor for RFID applications** (4 pages)
Xu Conghui, Gao Peijun, Che Wenyi, Tan Xi, Yan Na, and Min Hao
- 045004** **Design of an ultra-low-power digital processor for passive UHF RFID tags** (4 pages)
Shi Wanggen, Zhuang Yiqi, Li Xiaoming, Wang Xianghua, Jin Zhao, and Wang Dan
- 045005** **Design procedure for optimizing CMOS low noise operational amplifiers** (5 pages)
Li Zhiyuan, Ye Yizheng, and Ma Jianguo
- 045006** **A capacitor-free CMOS LDO regulator with AC-boosting and active-feedback frequency compensation** (6 pages)
Zhou Qianneng, Wang Yongsheng, and Lai Fengchang
- 045007** **A fast-settling frequency-presetting PLL frequency synthesizer with process variation compensation and spur reduction** (5 pages)
Yan Xiaozhou, Kuang Xiaofei, and Wu Nanjian
- 045008** **A 10 Gb/s receiver with half rate period calibration CDR and CTLE/DFE combiner** (7 pages)
Gao Zhuo, Yang Zongren, Zhao Ying, Yang Yi, Zhang Lu, Huang Lingyi, and Hu Weiwu
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Yuan Bing, Lai Xinquan, Li Yanming, Ye Qiang, and Jia Xinzhang

SEMICONDUCTOR TECHNOLOGY

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Ruan Wenbiao, Chen Lan, Li Zhigang, and Ye Tianchun